



### **General Description**

SY20466/SY20466A The high-efficiency synchronous Boost regulator has an input voltage range of 1.8V to 5.25V and can output an output voltage up to 5.5V. The device uses a NMOS MOSFET for the main switch and a PMOS for the synchronous switch. The output is disconnected from the input during shutdown mode and features programmable output-current limit using the ILIM pin.

The SY20466/SY20466A is available in a compact QFN2mmx2mm-10 package.

# **Applications**

Single-cell Lithium or Dual-Cell Nickel Battery-Powered Devices (MP3 players, PDAs, etc.)

### Features

- 1.8V Minimum Input Voltage
- Adjustable Output Voltage from 2.5V to 5.5V •
- 6A Peak Current Limit •
- Input Undervoltage Lockout •
- Quiescent Current: 27 µA (typ.) •
- Shutdown Current: 0.1 µA (typ.)
- Load Disconnect During Shutdown
- **Output Overvoltage Protection** •
- Input Battery Voltage Monitor •

100

98

96

94

92

90

88

86

84 0.0

Efficiency (%)

- Low R<sub>DS(ON)</sub> for Internal Switches at 5.0V Output: 20mΩ Main, 40mΩ Synchronous
- Automatic Output Discharge at Shutdown: • o SY20466: Automatic Output Discharge Function
  - o SY20466A: No Output Discharge Function

Efficiency vs. Load Current

V<sub>IN</sub>=2.0V,V<sub>OUT</sub>=5.0V

V<sub>IN</sub>=3.3V,V<sub>OUT</sub>=5.0V

V<sub>IN</sub>=4.2V,V<sub>OUT</sub>=5.0V

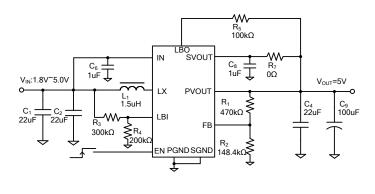
4.0

5.0

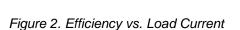
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Compact Package: QFN2mmx2mm-10

# **Typical Application**



#### Figure 1. Schematic Diagram



2.0

Load Current (A)

1.0

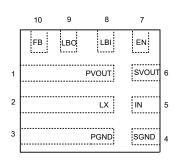


# **Ordering Information**

QFN2×2-10	
<b>RoHS-Compliant</b>	MG <i>xyz</i>
and Halogen-Free	-
QFN2×2-10	
<b>RoHS-Compliant</b>	Aa <i>xyz</i>
and Halogen-Free	-
	RoHS-Compliant and Halogen-Free QFN2x2-10 RoHS-Compliant

x = year code, y = week code, z = lot number code

# Pinout (top view)



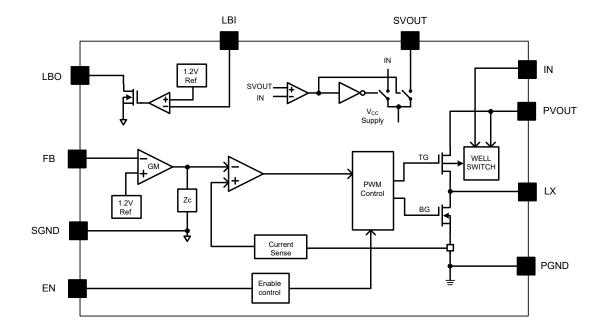
# Pin Description

Pin Name	Pin Number	Pin Description
PVOUT	1	Power output pin. Decouple this pin to the GND pin with at least a $22\mu$ F ceramic capacitor.
LX	2	Inductor pin. Connect an inductor between the IN pin and the LX pin.
PGND	3	Power ground pin.
SGND	4	Signal ground pin.
IN	5	Signal input pin. Decouple this pin to GND with at least a 4.7µF ceramic capacitor.
SVOUT	6	Signal output pin. Decouple this pin to GND with at least a 1µF ceramic capacitor for noise immunity consideration.
EN	7	Enable pin. Internally integrated $1M\Omega$ pulldown resistor.
LBI	8	Low-battery comparator input.
LBO	9	Low-battery comparator output (open-drain).
FB	10	Feedback pin. Connect a resistor R1 between OUT and FB, and a resistor R2 between FB and GND to program the output voltage. $V_{OUT} = 1.2V \times (R1/R2 + 1)$ .



# SY20466/SY20466A

# **Functional Block Diagram**



# **Absolute Maximum Ratings**

Parameter (Note 1)	Min	Max	Unit
EN		Vout+0.3	V
PVOUT, LX, IN, SVOUT, LBI, LBO, FB		6	-
Lead Temperature (Soldering, 10s)		260	
Junction Temperature, Operating	-40	150	°C
Storage Temperature	-65	150	

# **Thermal Information**

Parameter (Note 2)	Тур	Unit
θ <sub>JA</sub> Junction-to-Ambient Thermal Resistance	50	°C/W
θ <sub>JC</sub> Junction-to-Case Thermal Resistance	10	0,
$P_D$ Power Dissipation $T_{A=}25^{\circ}C$	2.5	W

### **Recommended Operating Conditions**

Parameter (Note 3)	Min	Max	Unit
IN	1.8	5.25	
PVOUT, SVOUT	2.5	5.5	V
EN	0	V <sub>OUT</sub> + 0.3	•
LX, LBI, LBO, FB	0	5.5	
Junction Temperature, Operating	-40	125	°C
Ambient Temperature	-40	85	Ũ



# **Electrical Characteristics**

$(V_{IN} = 2.4V, V_{OUT} = 5V, I_{OUT} = 500mA, T_A = 25^{\circ}C$ unless otherwise space of the transformation of transfor	pecified.)
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Parameter		Symbol	Test Conditions	Min	Тур	Max	Unit
Input Voltage		Vin		1.8		5.25	V
Output Voltage Rang	Output Voltage Range			2.5		5.5	V
	Vin		I <sub>0</sub> = 0A,		10		μA
Quiescent Current	Vout	lq	$V_{EN} = V_{IN} = 1.8V$ ,		27		μA
	V001		Vout = 5.0V				μΛ
Shutdown Current		ISHDN	$V_{EN}=0V,\ V_{IN}=2.4V$		0.1	1	μA
Linear Charge Curre	nt	ICHARGE	V <sub>OUT</sub> ≤ 1V		1.2		A
6	in the second seco	ICHARGE	1V < Vout < 90%Vin		1.0		7
Soft-Start Time		tss			1		ms
Input UVLO Thresho		V <sub>UVLO</sub>				1.78	V
Input UVLO Hysteres		V <sub>HYS</sub>			0.1		V
EN Rising Threshold		Venh		1.2			V
EN Falling Threshold	1	V <sub>ENL</sub>				0.4	V
LBI Voltage Threshold		V <sub>LBI</sub>		1.176	1.2	1.224	V
	LBI Input Hysteresis				20		mV
Low-Side Main FET	Ron	R <sub>DS(ON)1</sub>	$V_{OUT} = 5.0V$		20		mΩ
Synchronous FET R		RDS(ON)2	Vout = 5.0V		40		mΩ
Main FET Current Li		ILIM1		6.0			А
Switching Frequency		f <sub>sw</sub>			500		kHz
Feedback Reference	e Voltage	Vref		1.182	1.2	1.218	V
Output Overvoltage	Protection	Vovp			6		V
Minimum On-Time		t <sub>ON_MIN</sub>			100		ns
Minimum Off-Time		toff_min			100		ns
Max On-Time		ton_max			2		μs
Thermal Shutdown T	emperature	T <sub>SD</sub>			150		°C
Thermal Shutdown h	ysteresis	T <sub>HYS</sub>			20		°C
Output Discharge Re	esistor	Rdsc			80		Ω

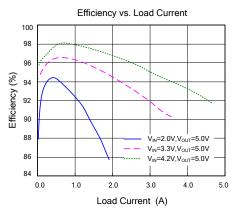
**Note 1**: Stresses beyond the "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specification is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

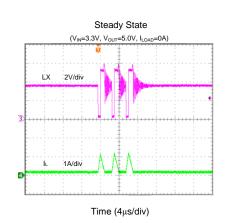
**Note 2**:  $\theta_{JA}$  is measured in the natural convection at  $T_A = 25^{\circ}C$  on a four-layer Silergy evaluation board.

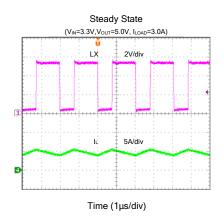
**Note 3:** The device is not guaranteed to function outside its operating conditions.

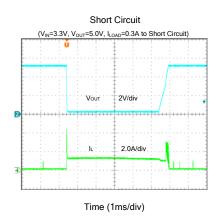


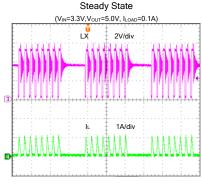
# **Typical Performance Characteristics**



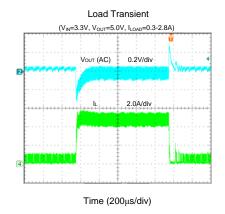






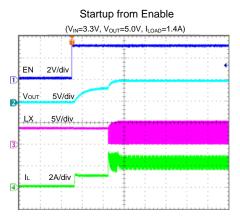


Time (10µs/div)

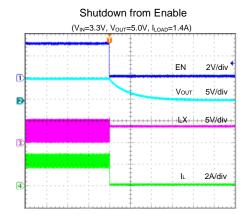




# SY20466/SY20466A



Time (1ms/div)



Time (400µs/div)



### **Application Information**

#### Operation

The SY20466/SY20466A uses constant-frequency peakcurrent control to regulate the output voltage. A PWM cycle initiated by the internal clock turns the bottom FET on, which remains on until its current reaches the value set by V<sub>COMP</sub>. When the PWM signal goes low, the bottom FET turns off and remains off until the next cycle starts. When V<sub>FB</sub> drops below the internal reference voltage (V<sub>REF</sub>), V<sub>COMP</sub> will be driven higher, so the switch peak current becomes higher and the IC delivers more energy to the output. Conversely, when V<sub>FB</sub> rises above V<sub>REF</sub>, the V<sub>COMP</sub> will be driven lower and the switch peak current output drops. See Figure 3 for details.

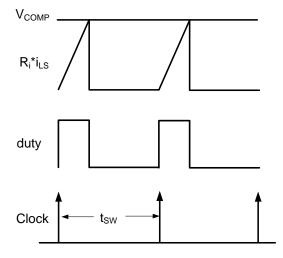


Figure 3. Constant-On-Time Peak-Current Control

The following paragraphs describe the selection process for the input capacitor  $C_{IN}$ , the output capacitor  $C_{OUT}$ , the inductor L, and the feedback resistor-divider (R1 and R2).

#### Feedback Resistor-Divider R1 and R2:

Choose R1 and R2 in the feedback resistor-divider to configure the output voltage. A value between  $10k\Omega$  and  $1M\Omega$  is recommended for both resistors to minimize power consumption under light loads. If  $V_{OUT} = 5.0V$  and R1 is chosen to be  $470k\Omega$ , then R2 can be calculated as  $148.4k\Omega$  using the following formula:

$$R_2 = \frac{1.2V}{V_{OUT} - 1.2V} R_1$$

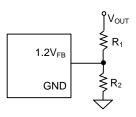


Figure 4. Feedback Resistor-Divider

#### Input Capacitor CIN

Input filter capacitors reduce the ripple voltage on the input, filter the switched current drawn from the input supply, and reduce potential EMI. When selecting an input capacitor, be sure to select a voltage rating at least 20% greater than the maximum voltage of the input supply and a temperature rating higher than the system requirements. X5R or X7R series ceramic capacitors are most often selected due to their small size, low cost, surge-current capability, and high RMS current ratings over a wide temperature and voltage range. Systems that are powered by a wall adapter or other long and therefore inductive cabling may be susceptible to significant inductive ringing at the input to the device. In these cases, consider adding some bulk capacitance like electrolytic, tantalum, or polymer type capacitors. Using a combination of bulk capacitors (to reduce overshoot or ringing) in parallel with ceramic capacitors (to meet the RMS current requirements) is helpful in these cases.

Consider the RMS current rating of the input capacitor, paralleling additional capacitors if required to meet the calculated RMS ripple current.

The ripple current through input capacitor is calculated as:

$$I_{CIN\_RMS} = \frac{V_{IN} \times (V_{OUT} - V_{IN})}{2\sqrt{3 \times L f_{SW} \times V_{OUT}}}$$

For the best performance, select a typical X5R or better grade ceramic capacitor with a 6.3V rating and at least  $22\mu$ F capacitance.



#### Li-Ion Battery Hot Plug Consideration

In the mass production stage, the Li-Ion battery will always hot plug between the IN and GND pins. The hot plug may lead to large voltage spikes, or even to device electrical overstress (EOS) failure. To avoid this potential risk, place one  $22\mu$ F ceramic capacitor in series with a 0.1 $\Omega$  resistor to absorb the input voltage spike. With this

solution, the voltage spike can be reduced from 6.12V to 5.2V in order to meet the device absolute maximum operating conditions. See Figures 5, 6, and 7 for more details.

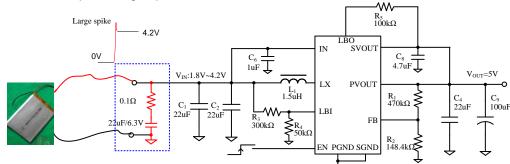


Figure 5. Voltage Spike Suppression

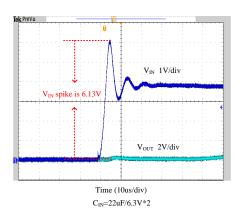


Figure 6. Voltage Spike without Suppression

#### Inductor L

Consider the following when choosing this inductor:

• Choose the inductance to provide a ripple current that is approximately 40% of the maximum output current. The recommended inductance is calculated as:

$$L = \left(\frac{V_{IN}}{V_{OUT}}\right)^2 \frac{(V_{OUT} - V_{IN})}{f_{SW} \times I_{OUT, MAX} \times 40\%}$$

where  $f_{\text{SW}}$  is the switching frequency and  $I_{\text{OUT\_MAX}}$  is the maximum load current.

The SY20466/SY20466A has high tolerance for ripplecurrent amplitude variation. As a result, the final choice of inductance can vary slightly from the calculated value with no significant performance impact.

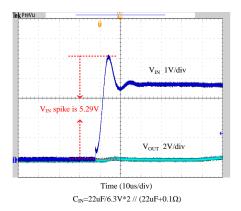


Figure 7. Voltage Spike with Suppression

• The saturation-current rating of the inductor must be selected to be greater than the peak inductor current under full-load conditions.

$$I_{\text{SAT,MIN}} > \left(\frac{V_{\text{OUT}}}{V_{\text{IN}}}\right) \times I_{\text{OUT,MAX}} + \frac{V_{\text{IN}}(V_{\text{OUT}} - V_{\text{IN}})}{2 \times f_{\text{SW}} \times L \times V_{\text{OUT}}}$$

 The DCR of the inductor and the core loss at the switching frequency must be low enough to achieve the desired efficiency requirement. Choose an inductor with DCR lower than 50mΩ to achieve a good overall efficiency.

#### **Output Capacitor COUT**

For applications where the design must meet stringent ripple requirements, the following considerations must be followed:



The output-voltage ripple at the switching frequency is caused by the inductor-current ripple ( $\Delta I_L$ ) on the output capacitor's ESR (ESR ripple), as well as the stored charge (capacitive ripple). When calculating total ripple, both should be considered.

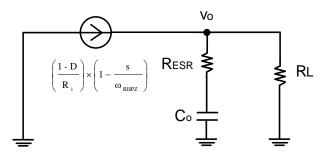
$$\begin{split} V_{\text{RIPPLE, ESR1}} &= I_{\text{LPEAK}} \times \text{ESR} \\ V_{\text{RIPPLE, ESR2}} &= I_{\text{LVALLEY}} \times \text{ESR} \\ V_{\text{RIPPLE, CAP}} &= \frac{I_{\text{OUT}} \times (1\text{-}D)}{C_{\text{OUT}} \times f_{\text{SW}}} \end{split}$$

The capacitive ripple might be higher because the effective capacitance for ceramic capacitors decreases with the voltage across the terminals. The voltage derating is usually included as a chart in the capacitor datasheet, and the ripple can be recalculated after taking the target output voltage into account.

#### Inductor vs. Output Capacitor

Select the output capacitor  $C_{OUT}$  to handle the output ripple requirements. Both steady-state ripple and transient requirements must be taken into consideration when selecting  $C_{OUT}$ . For the best performance, use an X5R or better grade ceramic capacitor with a 10V rating and a capacitance that is more than specified in Table1. Care should be taken to minimize the loop area formed by  $C_{OUT}$ and the OUT/GND pins. In some cases, reducing the number of ceramic capacitors and adding in parallel a tantalum capacitor with a 16V rating and at least 100µF capacitance can provide a lower cost solution.

All continuous-mode boost converters have a right-halfplane zero (RHP zero) due to the inductor being removed from the output during charging. In a converter with currentmode control, the current feedback loop allows the switch, inductor, and modulator to be lumped together into a small signal variable current source, as shown in Figure 8.



The power stage approximate transfer function is:

$$G_{c}(s) = \frac{(1-D) \times R_{L}}{R_{i}} \times \frac{\left(1 + \frac{s}{\omega_{ESR}}\right) \left(1 - \frac{s}{\omega_{RHPZ}}\right)}{1 + \frac{s}{\omega_{P}}}$$

where:

$$\omega_{\text{ESR}} = \frac{1}{R_{\text{ESR}}C_{\text{O}}}$$
$$\omega_{\text{P}} = \frac{1}{\left(R_{\text{ESR}} + R_{\text{L}}\right) \times C_{\text{O}}}$$
$$\omega_{\text{RHPZ}} = \frac{R_{\text{L}}}{L} \times \left(\frac{V_{\text{IN}}}{V_{\text{OUT}}}\right)^{2}$$

As Equation 6 shows, the transfer function for boost conversion with current-mode control consists of one ESR zero, one RHP zero, and one pole. The RHP zero provides a 20dB/decade gain increase and 90 degrees of phase drop. Therefore, the bandwidth of the boost converter must be lower than  $f_{\text{RHPZ}}$ .

As shown in Equation 9, the RHP zero depends on R2, L, and the duty cycle. Larger inductors lead to lower  $f_{RHPZ}$ , so bandwidth should be designed lower than  $f_{RHPZ}$ .

Some low-profile applications may benefit from using the ceramic capacitor solution, and some low-cost applications may benefit from using an electrolytic capacitor to reduce BOM cost.

Figure8. Current Feedback Loop



Inductance		Inductance Low-Profile Capacitor Application		Low-Cost Capacitor Application
Part Number	L(µH)	Part Number	C <sub>ουτ</sub> (μF)	С <sub>оит</sub> (µF)
SPM6530T-1R0M	1.0	C3216X5R1A226M	22µF/10V×3pcs	22µF/10V+100uF(E-cap)
SPM6530T-1R5M	1.5	C3216X5R1A226M	22µF/10V×4pcs	22µF/10V+100uF(E-cap)
SPM6530T-2R2M	2.2	C3216X5R1A226M	22µF/10V×5pcs	22µF/10V+200uF(E-cap)

#### Table 1. Inductance vs. Output Capacitor Selection

#### **Enable Operation**

Pulling the EN pin high (>1.2V) enables normal operation. Pulling the EN pin low (<0.4V) will shut down the device. During shutdown mode, the SY20466/SY20466A shutdown current drops to less than  $1\mu$ A.

#### Low-Battery Detector Function LBI/LBO

The low-battery detector function is used for monitoring the battery voltage and generating an error flag when the battery voltage drops below a user-defined threshold voltage.

This function is only active when the device is enabled. When the device is disabled, the LBO remains high impedance. The detection threshold is 1.2V at the LBI pin. During normal operation, the LBO remains high impedance when the voltage applied at LBI is above the threshold. It is active-low when the voltage at LBI goes below 1.2V.

The battery voltage at which the detection circuit switches can be programmed with a resistive divider connected to the LBI pin. The resistive divider scales down the battery voltage to a voltage level which is compared to the LBI threshold voltage. The LBI pin has a built-in hysteresis of 20mV. If the low-battery detection circuit is not used, the LBI pin should be connected to GND (or to the V<sub>BAT</sub>) and the LBO pin can be left unconnected. Do not leave the LBI pin floating.

R3 and R4 are designed to program the proper low-battery threshold voltage. The voltage across R4 is equal to the LBI voltage threshold that is generated on-chip, which has a value of 1.2V. The value of resistor R3, depending on the desired minimum battery voltage  $V_{BAT}$ , can be calculated as:

$$R_3 = \frac{V_{BAT} - 1.2V}{1.2V} R_4$$

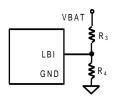


Figure 9. Low-Battery Threshold Setting

The output of the low-battery monitor is an open-drain output that goes active-low if the dedicated battery voltage drops below the programmed threshold voltage on the LBI. The output requires a pullup resistor with a recommended value of  $100k\Omega$ . The maximum voltage that is used for pulling up the LBO outputs should not exceed the output voltage of the DC/DC converter. If not used, the LBO pin can be left floating or tied to GND.

#### **Overvoltage Protection**

The SY20466/SY20466A provides output overvoltage protection. If the output voltage exceeds  $V_{OVP}$  (typ. 6V), the device stops switching, and the main switch is turned off. When the output voltage returns to the normal operating range, the device resumes operation.

#### **Overcurrent Protection**

The SY20466/SY20466A provides cycle-by-cycle overcurrent protection. If the current through the Low-Side MOSFET current reaches the 6A current-limit threshold, it turns off to prevent the input current from increasing further. In this case, the output voltage will decrease until power is balanced between input and output. As soon as the overload condition is removed, the converter resumes operation.

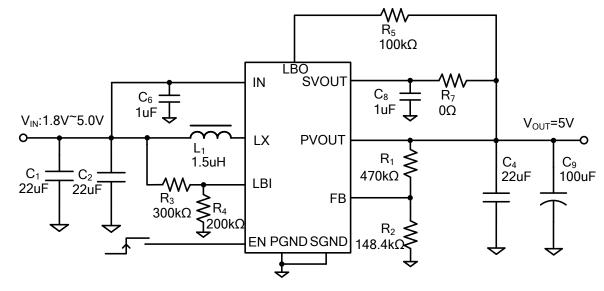
#### **Thermal Protection**

The SY20466/SY20466A includes overtemperature protection circuitry to prevent overheating due to excessive power dissipation. This will shut down the device when the junction temperature exceeds 150°C. When the junction temperature cools down by approximately 20°C, the device will resume normal operation after a complete soft-start



cycle. For continuous operation, provide adequate cooling so that the junction temperature does not exceed the thermal protection threshold.

# **Typical Application Schematic**



# **Design Specifications**

Input Voltage (V)	Output Voltage (V)	Output Current Limit (A)
1.8-5	5	3

### **BOM List**

Reference Designator	Description	Part Number	Manufacturer
L1	1.5µH/10A	ETQP3W-1R5AFN	SAMPLES
	1.5μπ/10Α	SPM6530T-1R5M	TDK
C1, C2	22µF/6.3V, 0805, X5R	C2012X5R1A226M	TDK
C4	22µF/10V, 1206, X5R	C3216X5R1A226M	TDK
C6	1µF/25V, 0603, X5R	C1608X5R1E105K	TDK
C8	1µF/25V, 0603, X5R	C1608X5R1E105K	TDK
C9	100µF/25V		
	Electrolytic Capacitor		
R1	470kΩ, 0603, 1%		
R2	150kΩ, 0603, 1%		
R3	300kΩ, 0603, 1%		
R4	200kΩ, 0603, 1%		
R5	100kΩ, 0603, 1%		
R6	1MΩ, 0603, 1%		
R7	0Ω, 0603		



### **Recommended Components for Typical Applications**

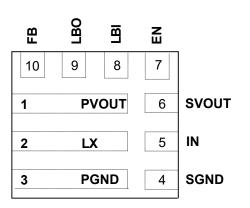
<b>V</b> оит <b>(V)</b>	R2(kΩ)	R1(kΩ)	L(µH)	Cout
5	470	150	1.5	22µF/10V/X5R,1206+100uF(E-cap)
3.3	510	300	1.5	22µF/6.3V/X5R,1206+100uF(E-cap)

### **Recommended PCB Layout**

Follow these PCB layout guidelines for optimal performance and thermal dissipation:

- Place the following components as close as possible to the IC: C<sub>IN</sub>, C<sub>OUT</sub>, L, R1, and R2.
- To achieve the best thermal and noise performance, maximize the PCB copper area connecting to the PGND pin. If board space allows, using a large copper pour connected to GND ground plane is recommended.
- C<sub>OUT</sub> must be close to the PVOUT and PGND pins. Minimize the loop area formed by C<sub>OUT</sub> and GND.
- To minimize the output loop area, route the LX trace on the bottom or middle layer through a via.

- SVOUT is the power supply pin for the internal control circuit. Do not connect to the POUT pin directly. A 4.7µF ceramic capacitor is recommended to decouple the SVOUT pin to the SGND pin. Use a trace to connect the SVOUT pin to the output capacitor.
- Minimize the PCB copper area associated with the LX pin to reduce EMI emissions.
- To avoid crosstalk, R1, R2, and the trace connecting to the FB pin must not be adjacent to the LX net on the PCB layout.



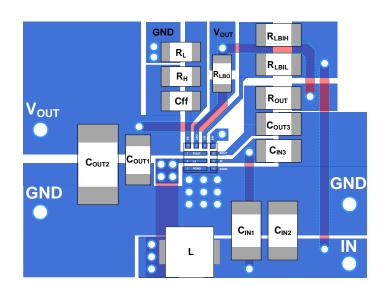
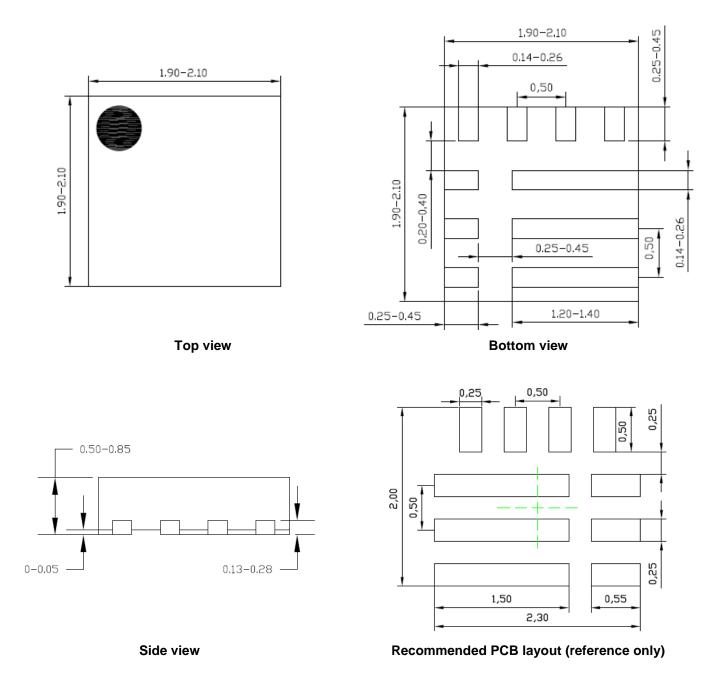


Figure 10. Suggested PCB Layout



# QFN2×2-10 Package Outline

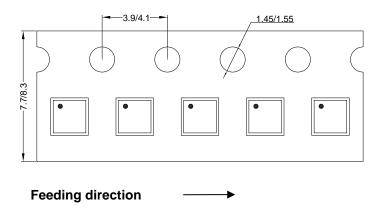


Note: All dimensions are in millimeters and exclude mold flash and metal burr.

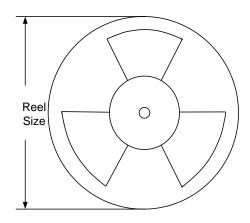


# **Taping and Reel Specification**

### QFN2×2 taping orientation



# Carrier tape and reel specification for packages



Package	Tape width	Pocket	Reel size	Trailer	Leader	Qty per reel
type	(mm)	pitch(mm)	(Inch)	length(mm)	length (mm)	(pcs)
QFN2x2	8	4	7"	400	160	3000

Others: NA



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